

Features

- Excellent Stability and Uniformity
- High Dense Cell Design For Extremely Low $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device ⁽¹⁾
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

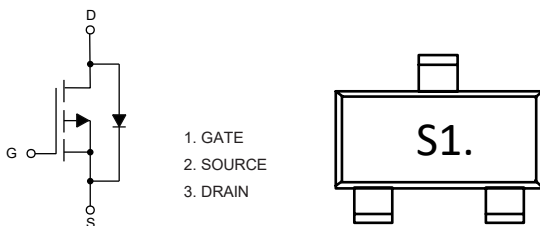
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 125°C/W Junction to Ambient(Steady-State)⁽²⁾

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	±8	V
Continuous Drain Current	I_D	$T_A=25^\circ\text{C}$	-2.8
		$T_A=100^\circ\text{C}$	-1.8
Pulsed Drain Current ⁽³⁾	I_{DM}	-10	A
Total Power Dissipation ⁽⁴⁾	P_D	1	W

Note:

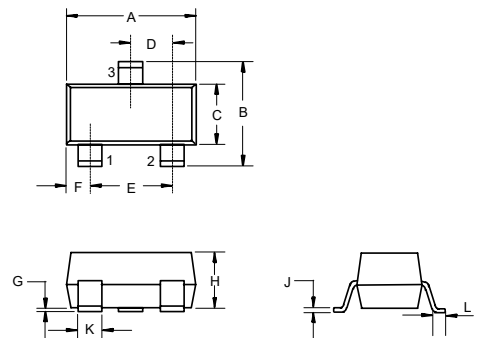
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^\circ\text{C}$. The Power dissipation P_{DSM} is based on $R_{\theta JA} \leq 10\text{s}$ and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction to ambient thermal resistance.

Internal Structure and Marking Code



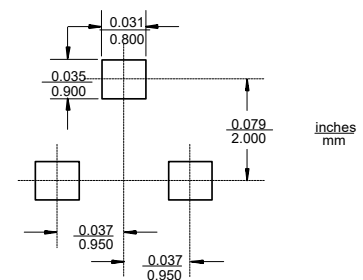
P-CHANNEL MOSFET

SOT-23



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.110	0.120	2.80	3.04	
B	0.083	0.104	2.10	2.64	
C	0.047	0.055	1.20	1.40	
D	0.034	0.041	0.85	1.05	
E	0.067	0.083	1.70	2.10	
F	0.018	0.024	0.45	0.60	
G	0.0004	0.004	0.01	0.10	
H	0.035	0.041	0.90	1.025	
J	0.003	0.007	0.08	0.18	
K	0.012	0.020	0.30	0.51	
L	0.007	0.020	0.20	0.50	

Suggested Solder Pad Layout



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-20			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 8V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-20V, V_{GS}=0V$			-1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.5	-0.7	-0.9	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-4.5V, I_D=-2.8A$		80	120	m Ω
		$V_{GS}=-2.5V, I_D=-2.0A$		110	150	
Gate Resistance	R_g	f=1 MHz, Open drain		15		Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				-2.8	A
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=-2.8A$			-1.2	V
Reverse Recovery Time	t_{rr}	$I_F=-1.4A, dI_F/dt=100A/\mu s$		28		ns
Reverse Recovery Charge	Q_{rr}			13		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=-6V, V_{GS}=0V, f=1MHz$		482		pF
Output Capacitance	C_{oss}			79		
Reverse Transfer Capacitance	C_{rss}			64		
Total Gate Charge	Q_g	$V_{DS}=-6V, V_{GS}=-4.5V, I_D=-2.8A$		5.4		nC
Gate-Source Charge	Q_{gs}			0.77		
Gate-Drain Charge	Q_{gd}			1.07		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-6V, V_{GS}=-4.5V, R_{GEN}=6\Omega, I_D=-1A$		7.26		ns
Turn-On Rise Time	t_r			8.18		
Turn-Off Delay Time	$t_{d(off)}$			46.72		
Turn-Off Fall Time	t_f			19.46		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

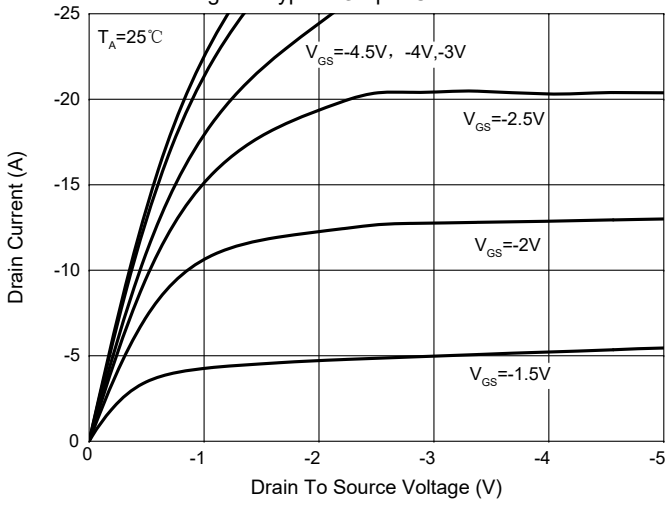


Fig. 2 - Transfer Characteristics

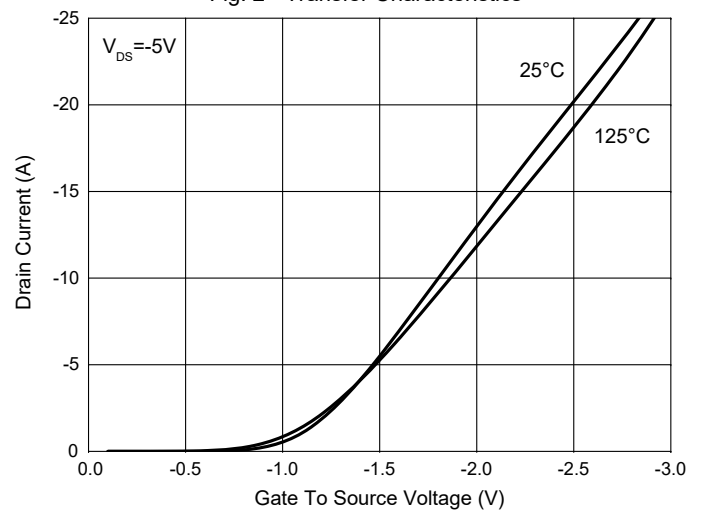


Fig. 3 - Capacitance Characteristics

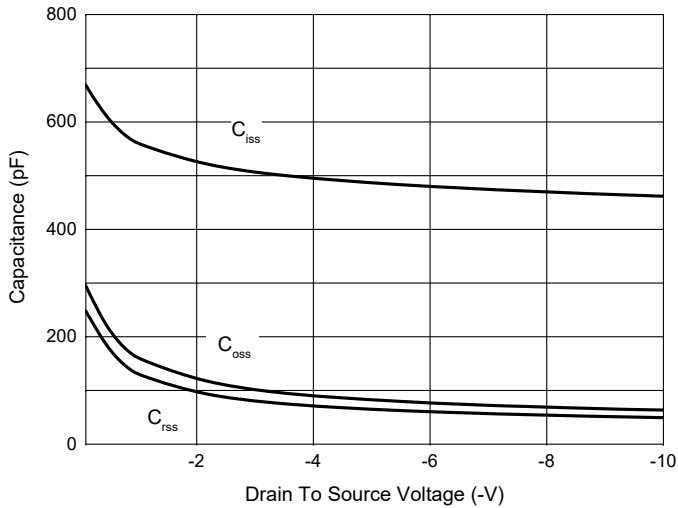


Fig. 4 - Normalized On Resistance Characteristics

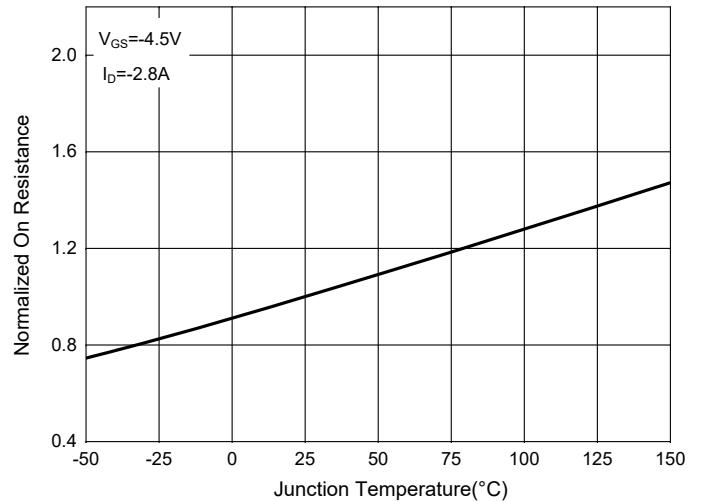


Fig. 5 - Gate Charge

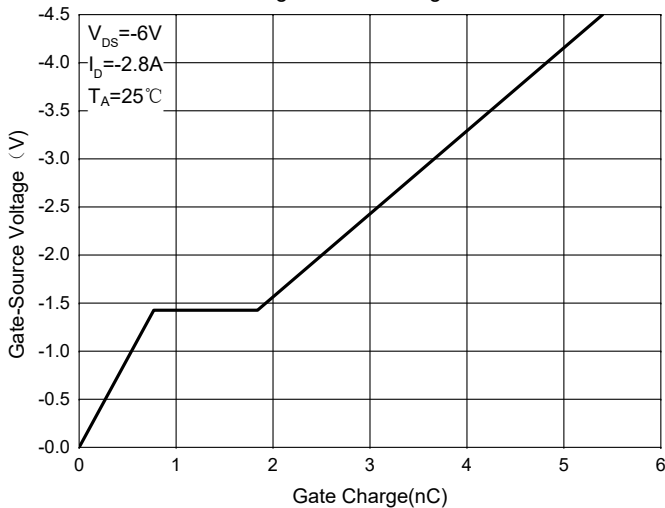
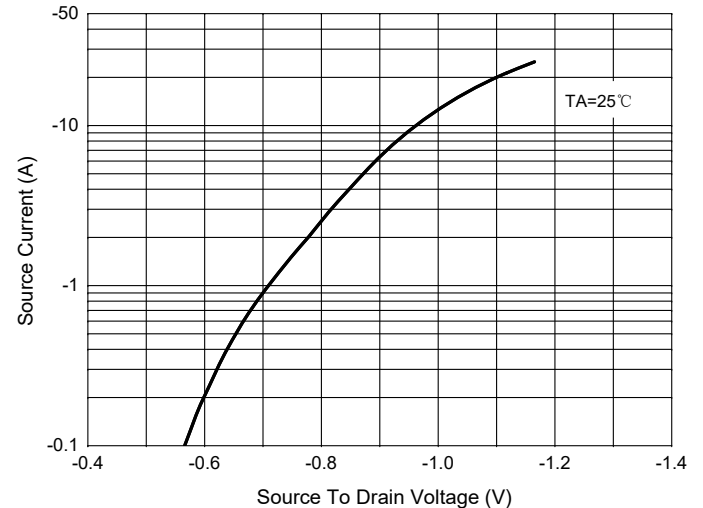


Fig. 6 - $I_S - V_{SD}$



Curve Characteristics

Fig. 7 - $R_{DS(ON)} - I_D$

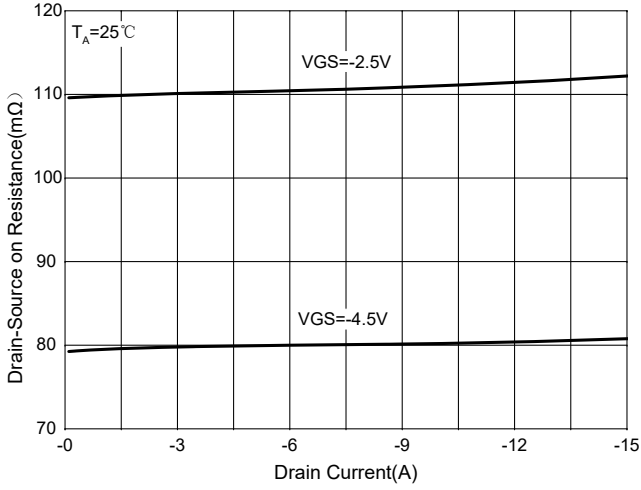


Fig. 8 - $V_{TH} - T_J$

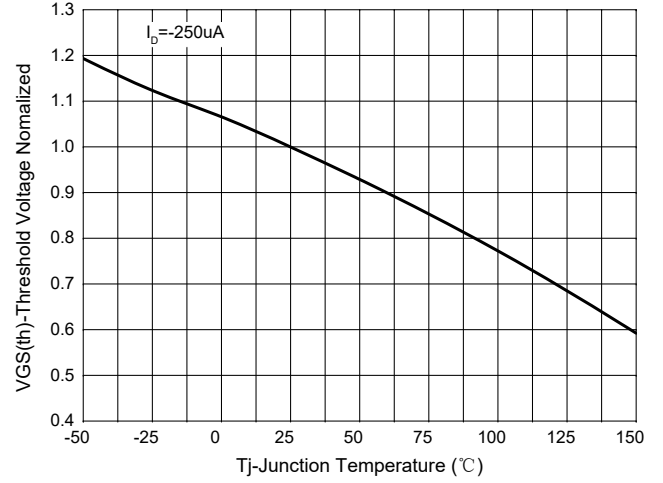


Fig. 9 - $R_{DS(ON)} - V_{GS}$

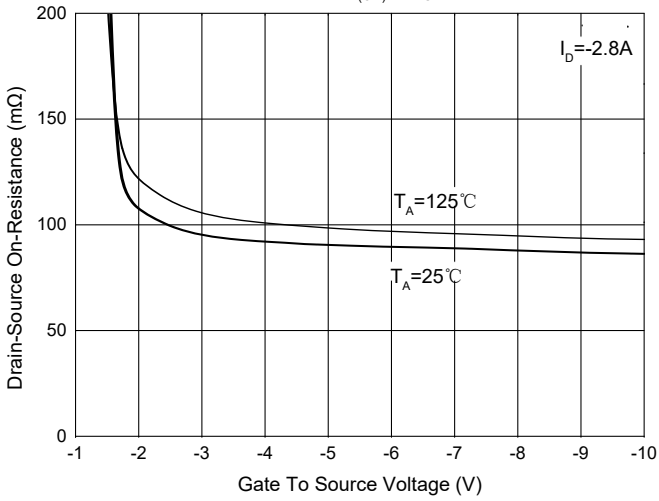


Fig. 10- Current dissipation

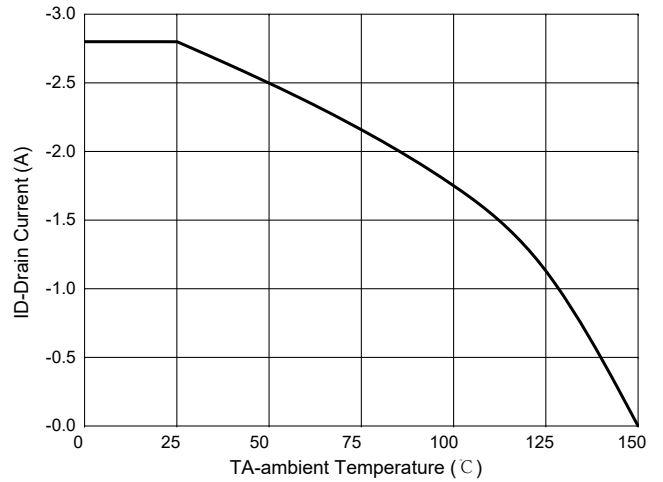
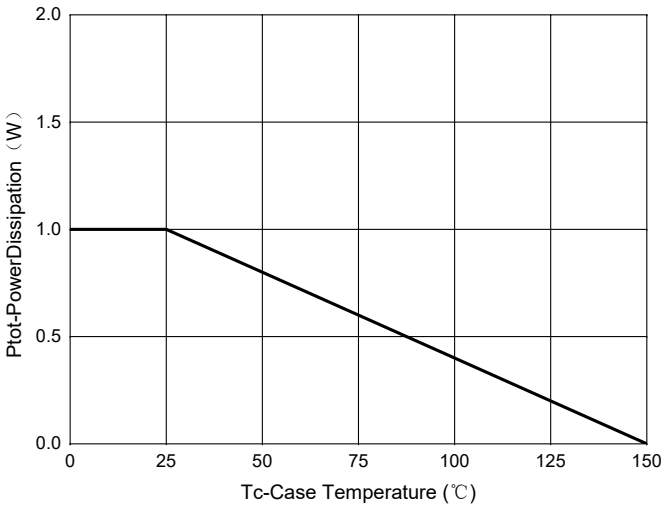


Fig. 11- Power Dissipation



Curve Characteristics

Fig. 12 - Safe Operation Area

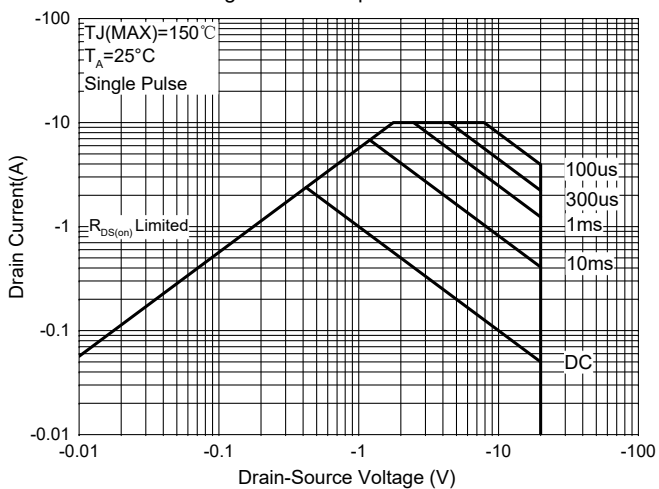
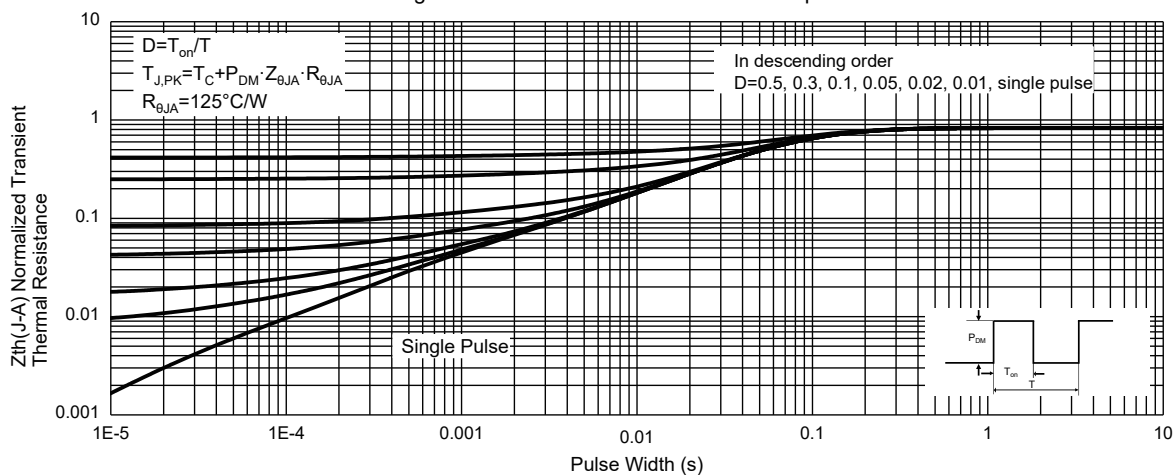


Fig. 13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel
Part Number-13P	Tape&Reel: 10Kpcs/Reel

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